

SiC Schottky Barrier Diode

V_R	1200V		
I _F	10A		
Q_{C}	34nC		

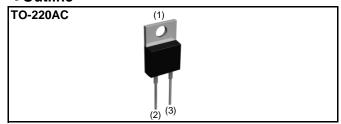
● Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

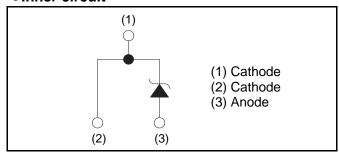
Construction

Silicon carbide epitaxial planer type

Outline



●Inner circuit



Packaging specifications

Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS210KG

● Absolute maximum ratings (Tj = 25°C)

Symbol	Value	Unit	
V_{RM}	1200	V	
V _R	1200	V	
I _F	10* ¹	А	
	45* ²	Α	
I _{FSM}	190* ³	Α	
	33*4	А	
I _{FRM}	46* ⁵	Α	
P _D	150* ⁶	W	
Tj	175	°C	
Tstg	-55 to +175	°C	
	V _{RM} V _R I _F I _{FSM} I _{FRM} P _D Tj	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	

^{*1} Tc=146°C *2 PW=8.3ms sinusoidal,Tj=25°C *3 PW=10μs square,Tj=25°C

^{*4} Pw=8.3ms sinusoidal, Tj=150°C, *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

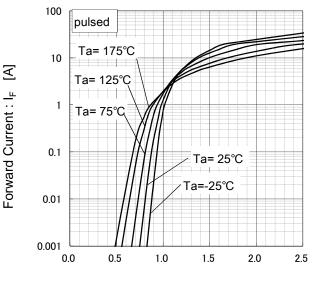
Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.2mA	1200	-	-	V
Forward voltage	V _F	I _F =10A,Tj=25°C	-	1.4	1.6	V
		I _F =10A,Tj=150°C	-	1.8	-	V
		I _F =10A,Tj=175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,Tj=25°C	-	10	200	μΑ
		V _R =1200V,Tj=150°C	-	80	-	μΑ
		V _R =1200V,Tj=175°C	-	130	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	550	-	pF
		V _R =800V,f=1MHz	-	42	-	pF
Total capacitive charge	Qc	V _R =800V,di/dt=500A/μs	-	34	-	nC
Switching time	tc	V _R =800V,di/dt=500A/μs	-	15	-	ns

●Thermal characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Thermal resistance	Rth(j-c)	-	-	0.73	0.99	°C/W

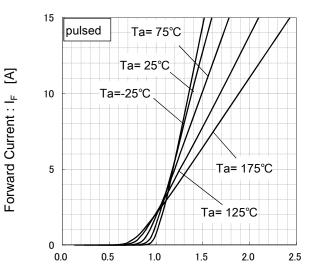
• Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



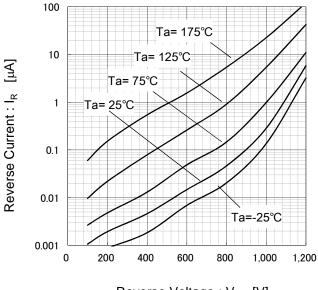
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



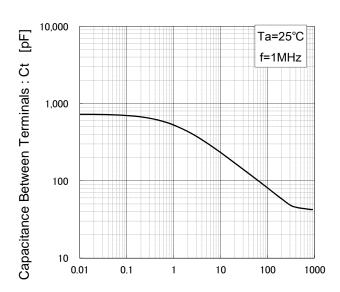
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

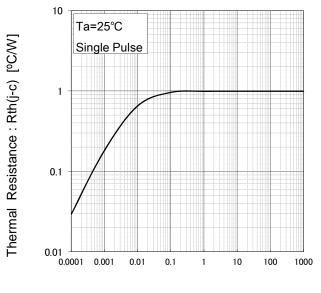
Fig.4 V_R-Ct Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

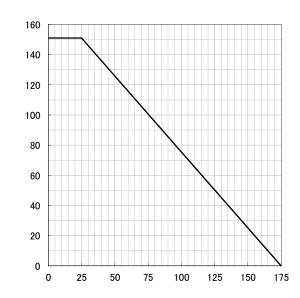
Fig.5 Thermal Resistance vs. Pulse Width



Pulse Width: Pw [s]

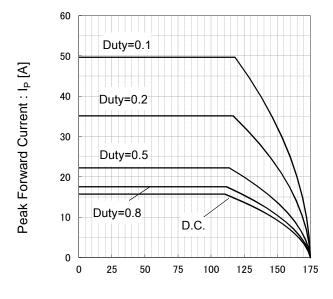
Fig.6 Power Dissipation

Power Dissipation [W]



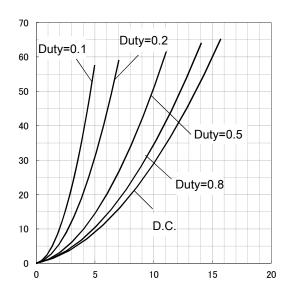
Case Temperature : Tc [°C]

Fig.7 Derating Curve Ip-Tc



Case Temperature : Tc [°C]

Fig.8 Io-Pf Characteristics

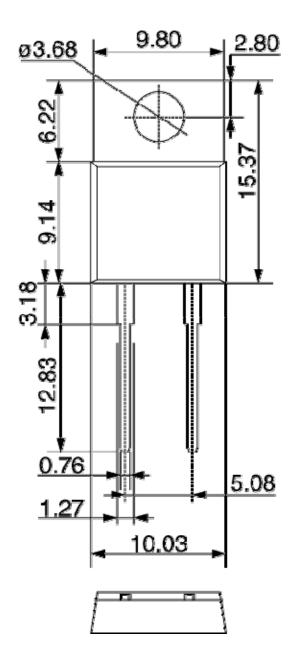


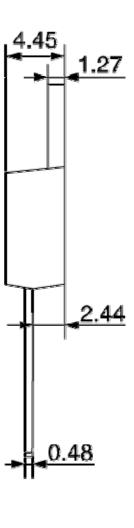
Average Rectified Forward Current : Io [A]

Power Dissipation [W]

●Dimensions (Unit : mm)

TO-220AC





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